

H5N5005PL-E0-E

500V - 60A - MOS FET
High Speed Power Switching

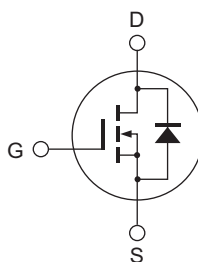
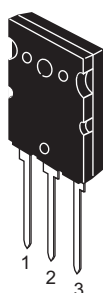
R07DS1199EJ0300
Rev.3.00
Mar 25, 2014

Features

- Low on-resistance
 $R_{DS(on)} = 0.070 \Omega$ typ. (at $I_D = 30 A$, $V_{GS} = 10 V$, $T_a = 25^\circ C$)
- Low leakage current
- High speed switching
- Low gate charge
- Avalanche ratings
- Built-in fast recovery diode

Outline

RENESAS Package code: PRSS0003ZC-A
(Package name:TO-264)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

($T_a = 25^\circ C$)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	500	V
Gate to Source voltage	V_{GSS}	± 30	V
Drain current	I_D	60	A
Drain peak current	$I_{D (pulse)}$ ^{Note1}	240	A
Body-Drain diode reverse Drain current	I_{DR}	60	A
Body-Drain diode reverse Drain peak current	$I_{DR (pulse)}$ ^{Note1}	240	A
Avalanche current	I_{AP} ^{Note3}	30	A
Channel dissipation	P_{ch} ^{Note2}	270	W
Channel to case thermal impedance	θ_{ch-c}	0.463	$^\circ C/W$
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
 2. Value at $T_c = 25^\circ C$
 3. $STch = 25^\circ C$, $T_{ch} \leq 150^\circ C$

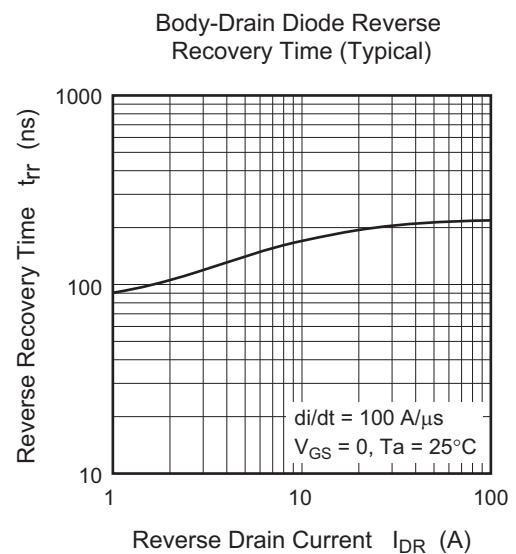
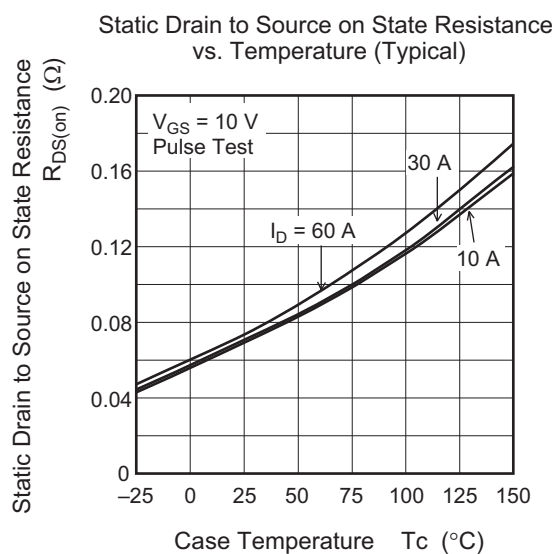
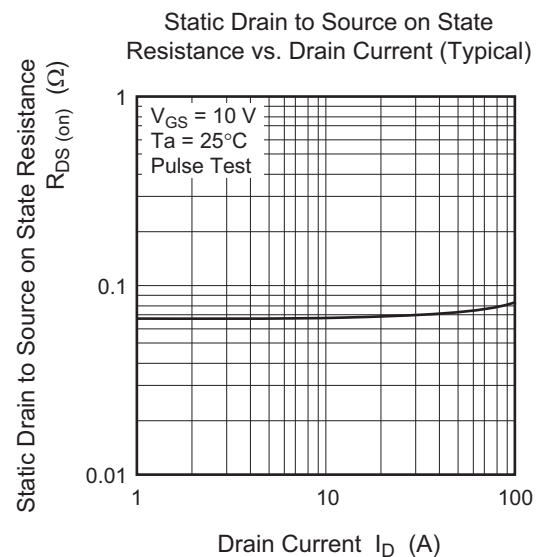
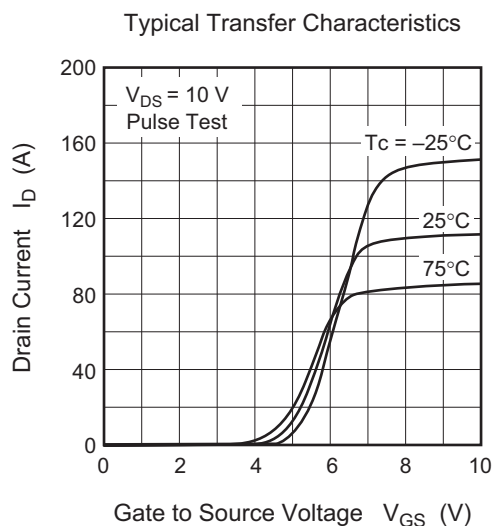
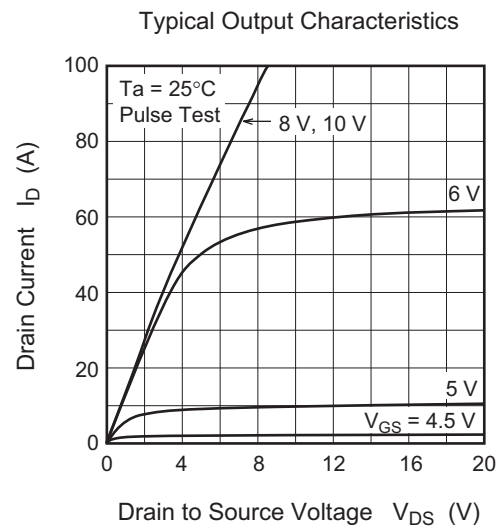
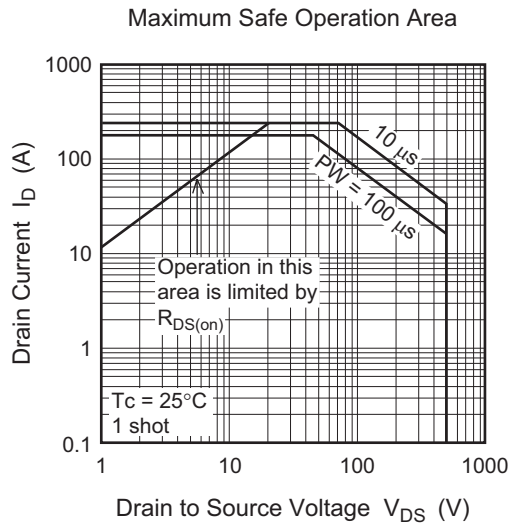
Electrical Characteristics

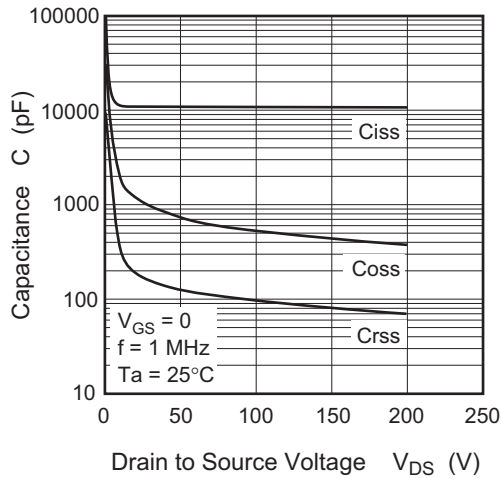
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	500	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero Gate voltage Drain current	I_{DSS}	—	—	10	μA	$V_{DS} = 500 \text{ V}$, $V_{GS} = 0$
Gate to Source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	25	42	—	S	$I_D = 30 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note4}
Static Drain to Source on state resistance	$R_{DS(on)}$	—	0.070	0.085	Ω	$I_D = 30 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	10550	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	C_{oss}	—	1060	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	180	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	115	—	ns	$I_D = 30 \text{ A}$
Rise time	t_r	—	380	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	560	—	ns	$R_L = 8.33 \Omega$
Fall time	t_f	—	300	—	ns	$R_g = 10 \Omega$
Total Gate charge	Q_g	—	300	—	nC	$V_{DD} = 400 \text{ V}$
Gate to Source charge	Q_{gs}	—	40	—	nC	$V_{GS} = 10 \text{ V}$
Gate to Drain charge	Q_{gd}	—	155	—	nC	$I_D = 60 \text{ A}$
Body-Drain diode forward voltage	V_{DF}	—	1.0	1.5	V	$I_F = 60 \text{ A}$, $V_{GS} = 0$ ^{Note4}
Body-Drain diode reverse recovery time	t_{rr}	—	220	—	ns	$I_F = 60 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$
Body-Drain diode reverse recovery charge	Q_{rr}	—	2.0	—	μC	

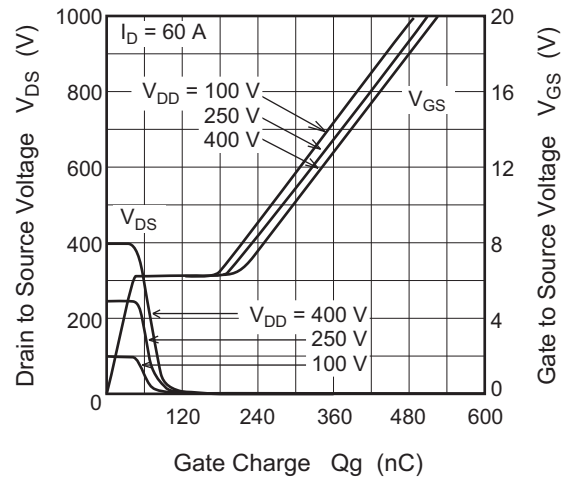
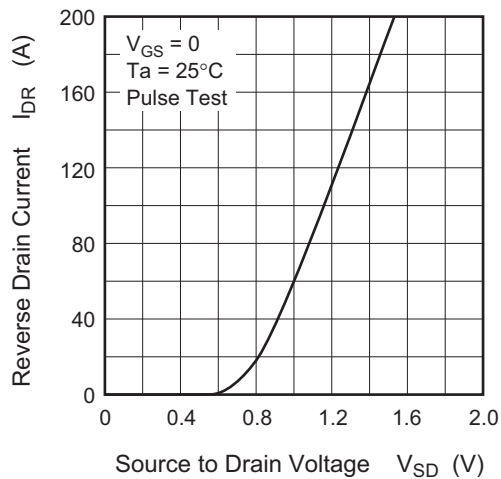
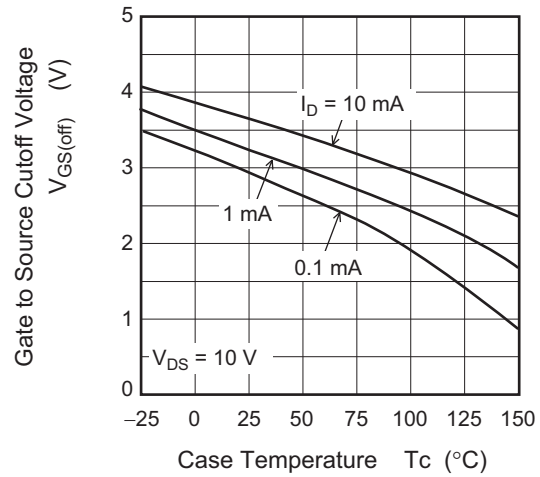
Note: 4. Pulse test

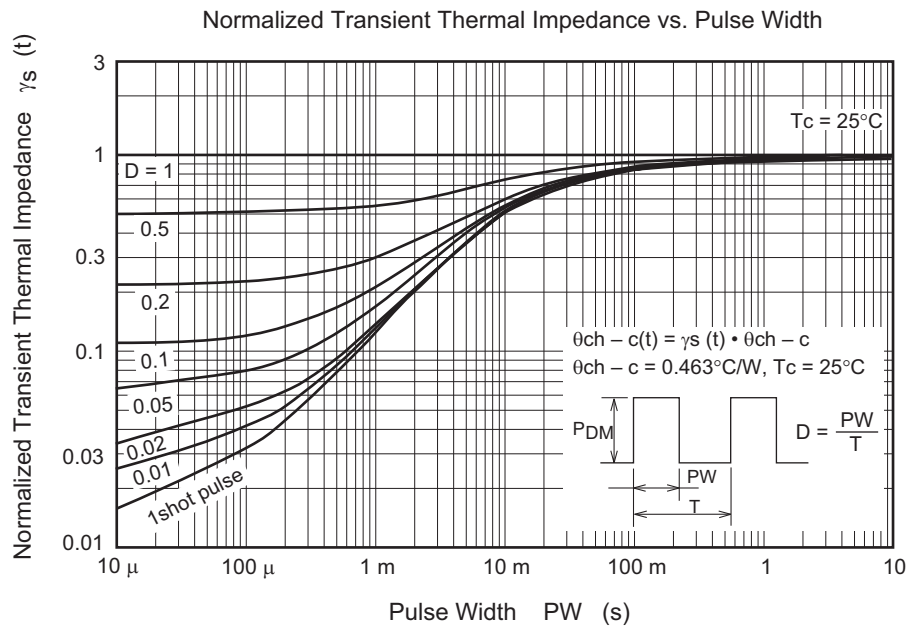
Main Characteristics



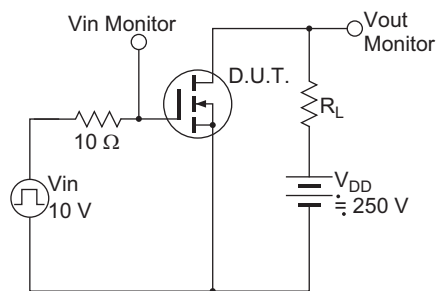
Typical Capacitance vs.
Drain to Source Voltage

Dynamic Input Characteristics (Typical)

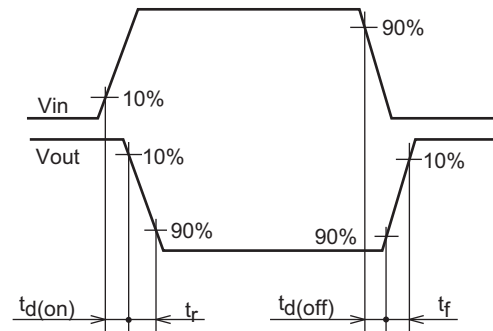
Reverse Drain Current vs.
Source to Drain Voltage (Typical)Gate to Source Cutoff Voltage
vs. Case Temperature (Typical)



Switching Time Test Circuit



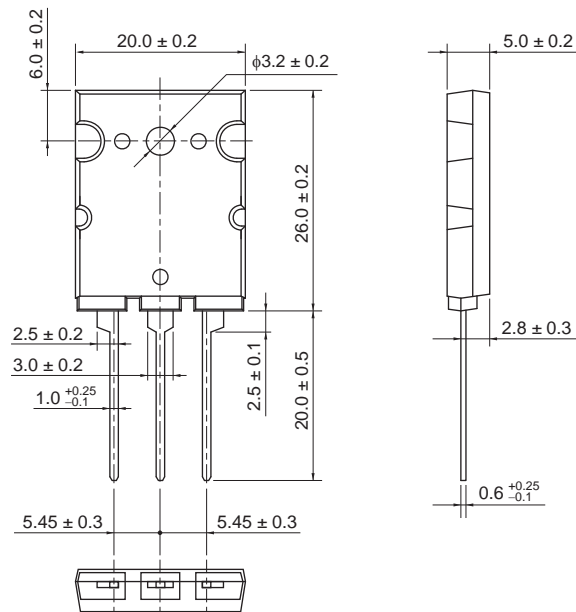
Waveform



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-264	—	PRSS0003ZC-A	TO-264S	9.48g

Unit: mm



Ordering Information

Orderable Part Number	Quantity	Shipping Container
H5N5005PL-E0-E#T2	25 pcs	Tube

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Renesas Electronics America Inc.

2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited

1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.

Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited

Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.

80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.

12F., 234 Teheran-ro, Gangnam-Ku, Seoul, 135-920, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141